

1A, 50V - 1000V High Efficient Surface Mount Rectifier

FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- Ultrafast recovery time for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Lighting application
- Snubber
- Freewheeling application

MECHANICAL DATA

- Case: DO-214AC (SMA)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.060g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	1	A
V_{RRM}	50 - 1000	V
I_{FSM}	30	A
T_{JMAX}	150	°C
Package	DO-214AC (SMA)	
Configuration	Single die	



DO-214AC (SMA)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)										
PARAMETER	SYMBOL	US1A	US1B	US1D	US1G	US1J	US1K	US1M	UNIT	
Marking code on the device		US1A	US1B	US1D	US1G	US1J	US1K	US1M		
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V	
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V	
Forward current	I_F	1								A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	30								A
Junction temperature	T_J	- 55 to +150								°C
Storage temperature	T_{STG}	- 55 to +150								°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance	$R_{\theta JL}$	27	°C/W
Junction-to-ambient thermal resistance	$R_{\theta JA}$	75	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage ⁽¹⁾	US1A US1B US1D US1G	$I_F = 1\text{A}, T_J = 25^\circ\text{C}$	V_F	-	1.0	V
	US1J US1K US1M			-	1.7	V
Reverse current @ rated V_R ⁽²⁾		$T_J = 25^\circ\text{C}$	I_R	-	5	μA
		$T_J = 125^\circ\text{C}$		-	150	μA
Junction capacitance	US1A US1B US1D US1G	1MHz, $V_R = 4.0\text{V}$	C_J	15	-	pF
	US1J US1K US1M			10	-	pF
Reverse recovery time	US1A US1B US1D US1G	$I_F = 0.5\text{A}, I_R = 1.0\text{A},$ $I_{rr} = 0.25\text{A}$	t_{rr}	-	50	ns
	US1J US1K US1M			-	75	ns

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION		
ORDERING CODE⁽¹⁾	PACKAGE	PACKING
US1x	DO-214AC (SMA)	7,500 / Tape & Reel

Notes:

1. "x" defines voltage from 50V(US1A) to 1000V(US1M)

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

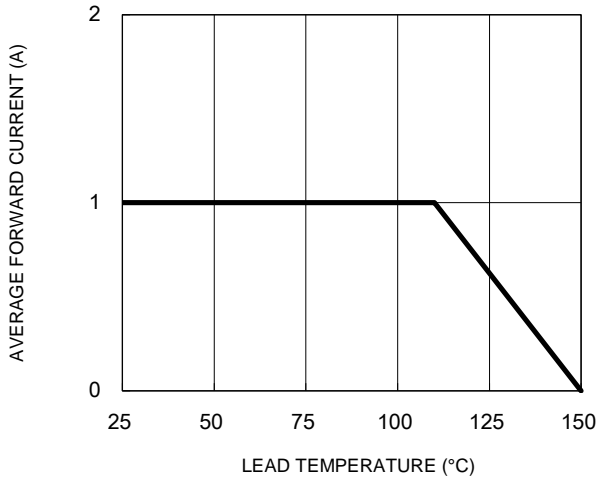


Fig.2 Typical Junction Capacitance

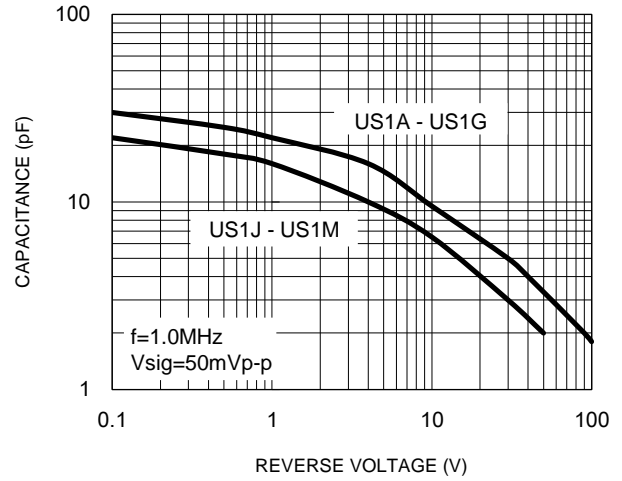


Fig.3 Typical Reverse Characteristics

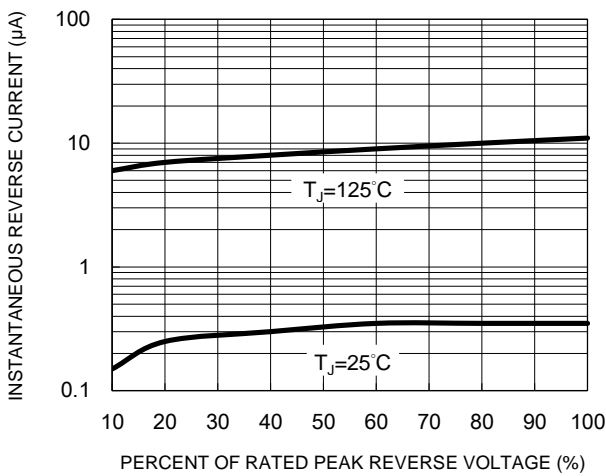


Fig.4 Typical Forward Characteristics

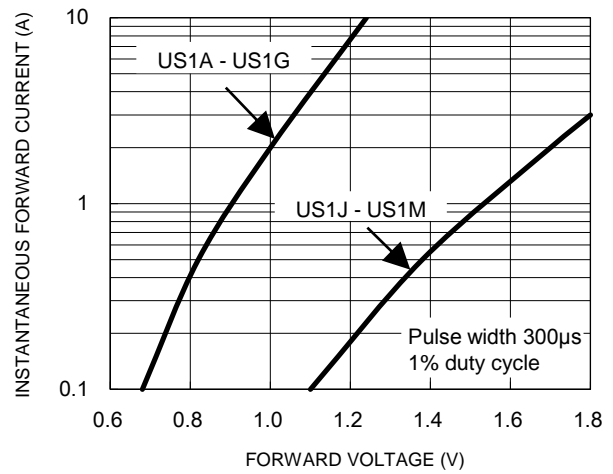
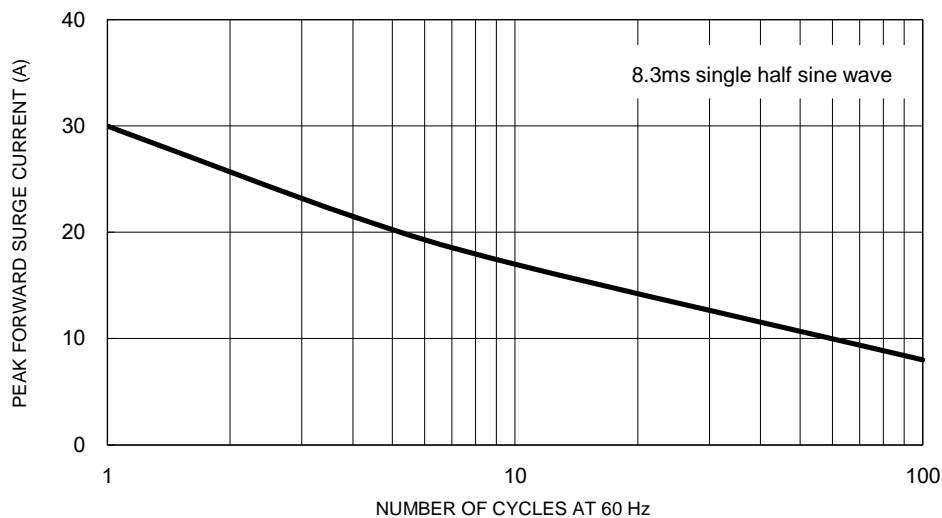


Fig.5 Maximum Non-Repetitive Forward Surge Current



CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.6 Typical Transient Thermal Characteristics

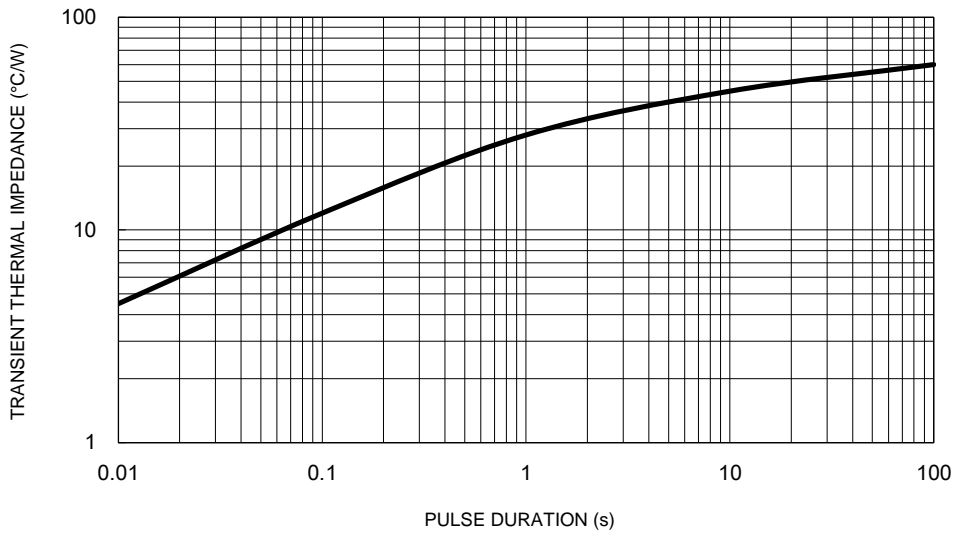
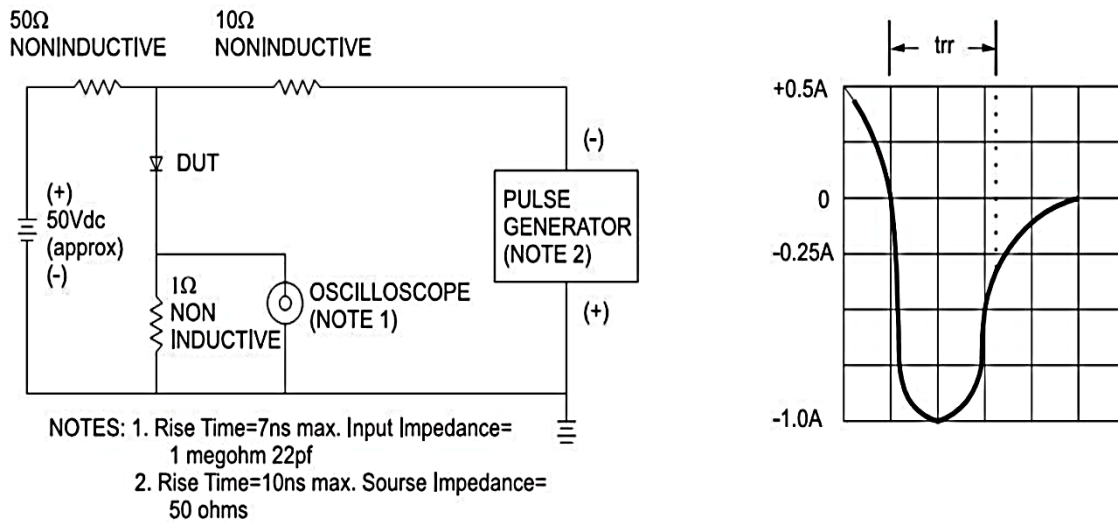
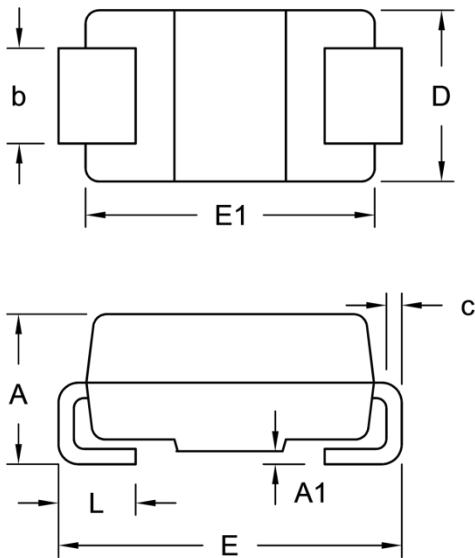


Fig.7 Reverse Recovery Time Characteristic And Test Circuit Diagram



PACKAGE OUTLINE DIMENSIONS

DO-214AC (SMA)



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	1.99	2.50	0.078	0.098
A1	0.10	0.20	0.004	0.008
b	1.27	1.58	0.050	0.062
c	0.15	0.31	0.006	0.012
D	2.29	2.83	0.090	0.111
E	4.95	5.33	0.195	0.210
E1	4.06	4.60	0.160	0.181
L	0.90	1.41	0.035	0.056

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.68	0.066
B	1.52	0.060
C	3.93	0.155
D	2.41	0.095
E	5.45	0.215

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YW = Date Code
- F = Factory Code